# 750 MHz Voltage Feedback Op Amp with **Fast Enable Feature**

NCS2552 is a 750 MHz voltage feedback monolithic operational amplifier featuring high slew rate and low differential gain and phase error. The voltage feedback architecture allows for a superior bandwidth and low power consumption. This device features an enable pin.

### **Features**

- -3.0 dB Small Signal BW ( $A_V = +2.0, V_O = 0.5 V_{p-p}$ ) 750 MHz Typ
- Slew Rate 1700 V/us
- Fast Enable Time 5.0 ns
- Supply Current 13 mA
- Input Referred Voltage Noise 5.0  $nV/\sqrt{Hz}$
- THD -64 dBc (f = 5.0 MHz,  $V_0 = 2.0 V_{p-p}$ )
- Output Current 100 mA
- Pin Compatible with EL5157, AD8057
- This is a Pb-Free Device

## **Applications**

- Line Drivers
- Radar/Communication Receivers

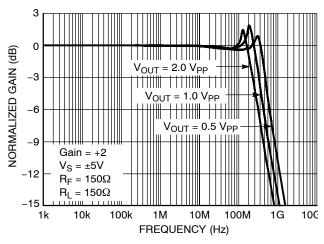


Figure 1. Frequency Response: Gain (dB) vs. Frequency Av = +2.0



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### **MARKING** DIAGRAM



SOT23-6 (TSOP-6) **SN SUFFIX CASE 318G** 



YF2, N2552 = NCS2552

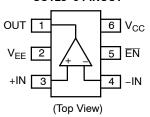
= Assembly Location Α

= Year

W = Work Week

= Pb-Free Package

#### SOT23-6 PINOUT



#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

# PIN FUNCTION DESCRIPTION

| Pin<br>(SOT23/SC70) | Symbol          | Function              | Equivalent Circuit                        |
|---------------------|-----------------|-----------------------|---|
| 1                   | OUT             | Output                | V <sub>CC</sub> SSD OUT OUT VEE           |
| 2                   | V <sub>EE</sub> | Negative Power Supply |   |
| 3                   | +IN             | Non-inverted Input    | V <sub>CC</sub> ESD  -IN  V <sub>EE</sub> |
| 4                   | -IN             | Inverted Input        | See Above                                 |
| 6                   | V <sub>CC</sub> | Positive Power Supply |   |
| 5                   | ĒN              | Enable                | EN ESD VEE                                |

# **ENABLE PIN TRUTH TABLE**

|        | High     | Low*    |
|--------|----------|---------|
| Enable | Disabled | Enabled |

<sup>\*</sup>Default open state

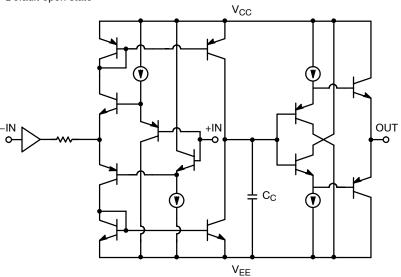


Figure 2. Simplified Device Schematic

#### **ATTRIBUTES**

| Characteristics   | Value                     |
|---|---------------------------|
| ESD Human Body Model Machine Model Charged Device Model | 2.0 kV<br>200 V<br>1.0 kV |
| Moisture Sensitivity (Note 1)                           | Level 1                   |
| Flammability Rating Oxygen Index: 28 to 34              | UL 94 V-0 @ 0.125 in      |

<sup>1.</sup> For additional information, see Application Note AND8003/D.

## **MAXIMUM RATINGS**

| Parameter                             | Symbol           | Rating          | Unit |
|---------------------------------------|------------------|-----------------|------|
| Power Supply Voltage                  | V <sub>S</sub>   | 11              | Vdc  |
| Input Voltage Range                   | V <sub>I</sub>   | ≤V <sub>S</sub> | Vdc  |
| Input Differential Voltage Range      | V <sub>ID</sub>  | ≤V <sub>S</sub> | Vdc  |
| Output Current                        | I <sub>O</sub>   | 100             | mA   |
| Maximum Junction Temperature (Note 2) | TJ               | 150             | °C   |
| Operating Ambient Temperature         | T <sub>A</sub>   | -40 to +85      | °C   |
| Storage Temperature Range             | T <sub>stg</sub> | -60 to +150     | °C   |
| Power Dissipation                     | P <sub>D</sub>   | (See Graph)     | mW   |
| Thermal Resistance, Junction-to-Air   | $R_{	hetaJA}$    | 158             | °C/W |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **MAXIMUM POWER DISSIPATION**

The maximum power that can be safely dissipated is limited by the associated rise in junction temperature. For the plastic packages, the maximum safe junction temperature is 150°C. If the maximum is exceeded momentarily, proper circuit operation will be restored as soon as the die temperature is reduced. Leaving the device in the "overheated" condition for an extended period can result in device damage.

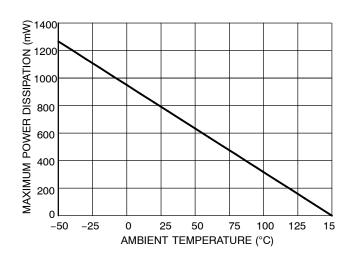


Figure 3. Power Dissipation vs. Temperature

<sup>2.</sup> Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded.

**AC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +5.0 V,  $V_{EE}$  = -5.0 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 150  $\Omega$  to GND,  $R_F$  = 150  $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

| Symbol                        | Characteristic  | Conditions   | Min | Тур        | Max | Unit   |
|-------------------------------|---|--|-----|------------|-----|--------|
| FREQUENC                      | CY DOMAIN PERFORMANCE                                   |  | •   | •          | •   | •      |
| BW                            | Bandwidth<br>3.0 dB Small Signal<br>3.0 dB Large Signal | $A_V = +2.0, V_O = 0.5 V_{p-p}$<br>$A_V = +2.0, V_O = 2.0 V_{p-p}$ |     | 750<br>350 |     | MHz    |
| GF <sub>0.1dB</sub>           | 0.1 dB Gain Flatness<br>Bandwidth                       | A <sub>V</sub> = +2.0  |     | 40         |     | MHz    |
| dG                            | Differential Gain                                       | $A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$                       |     | 0.07       |     | %      |
| dΡ                            | Differential Phase                                      | $A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$                       |     | 0.01       |     | ٥      |
| TIME DOM                      | AIN RESPONSE  |  |     |            |     |        |
| SR                            | Slew Rate   | $A_V = +2.0, V_{step} = 2.0 V$                                     |     | 1700       |     | V/μs   |
| t <sub>s</sub>                | Settling Time<br>0.1%                                   | A <sub>V</sub> = +2.0, V <sub>step</sub> = 2.0 V                   |     | 10         |     | ns     |
| t <sub>r</sub> t <sub>f</sub> | Rise and Fall Time                                      | (10%-90%) A <sub>V</sub> = +2.0, V <sub>step</sub> = 2.0 V         |     | 2.0        |     | ns     |
| t <sub>ON</sub>               | Turn-on Time  |  |     | 5.0        |     | ns     |
| t <sub>OFF</sub>              | Turn-off Time   |  |     | 15         |     | ns     |
| HARMONIC                      | NOISE PERFORMANCE                                       |  |     |            |     |        |
| THD                           | Total Harmonic Distortion                               | $f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$                           |     | -64        |     | dB     |
| HD2                           | 2nd Harmonic Distortion                                 | $f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$                           |     | -65        |     | dBc    |
| HD3                           | 3rd Harmonic Distortion                                 | $f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$                           |     | -75        |     | dBc    |
| IP3                           | Third-Order Intercept                                   | f = 10 MHz, V <sub>O</sub> = 1.0 V <sub>p-p</sub>                  |     | 40         |     | dBm    |
| SFDR                          | Spurious-Free Dynamic<br>Range                          | $f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$                           |     | 55         |     | dBc    |
| e <sub>N</sub>                | Input Referred Voltage Noise                            | f = 1.0 MHz  |     | 5.0        |     | nV/√Hz |
| i <sub>N</sub>                | Input Referred Current Noise                            | f = 1.0 MHz  |     | 4.0        |     | pA/√Hz |

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +5.0 V,  $V_{EE}$  = -5.0 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 150  $\Omega$  to GND,  $R_F$  = 150  $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).Closed Loop Open Loop

| Symbol                          | Characteristic                                  | Conditions               | Min  | Тур       | Max  | Unit  |
|---------------------------------|---|--------------------------|------|-----------|------|-------|
| DC PERFO                        | RMANCE  |                          |      |           |      |       |
| V <sub>IO</sub>                 | Input Offset Voltage                            |                          | -10  | 0         | +10  | mV    |
| $\Delta V_{IO}/\Delta T$        | Input Offset Voltage<br>Temperature Coefficient |                          |      | 6.0       |      | μV/°C |
| I <sub>IB</sub>                 | Input Bias Current                              | V <sub>O</sub> = 0 V     |      | ±3.2      | ± 20 | μΑ    |
| $\Delta I_{\text{IB}}/\Delta T$ | Input Bias Current<br>Temperature Coefficient   | V <sub>O</sub> = 0 V     |      | ± 40      |      | nA/°C |
| V <sub>IH</sub>                 | Input High Voltage (Enable)<br>(Note 3)         |                          | 3.0  |           |      | V     |
| V <sub>IL</sub>                 | Input Low Voltage (Enable)<br>(Note 3)          |                          |      |           | 1.0  | V     |
| INPUT CHA                       | ARACTERISTICS                                   |                          |      | •         |      |       |
| $V_{CM}$                        | Input Common Mode Voltage<br>Range (Note 3)     |                          | ±3.0 | ±3.2      |      | V     |
| CMRR                            | Common Mode Rejection<br>Ratio                  | (See Graph)              | 40   | 50        |      | dB    |
| R <sub>IN</sub>                 | Input Resistance                                |                          |      | 4.5       |      | MΩ    |
| C <sub>IN</sub>                 | Differential Input<br>Capacitance               |                          |      | 1.0       |      | pF    |
| оитрит с                        | HARACTERISTICS                                  |                          | •    | •         | •    |       |
| R <sub>OUT</sub>                | Output Resistance                               | Closed Loop<br>Open Loop |      | 0.1<br>13 |      | Ω     |
| Vo                              | Output Voltage Range                            |                          | ±3.0 | ±4.0      |      | V     |
| I <sub>O</sub>                  | Output Current                                  |                          | ±50  | ±100      |      | mA    |
| POWER SU                        | JPPLY   |                          |      |           |      |       |
| V <sub>S</sub>                  | Operating Voltage Supply                        |                          |      | 10        |      | V     |
| I <sub>S,ON</sub>               | Power Supply Current –<br>Enabled               |                          | 5.0  | 13        | 17   | mA    |
| I <sub>S,OFF</sub>              | Power Supply Current –<br>Disabled              |                          |      | 0.5       | 0.8  | mA    |
| PSRR                            | Power Supply Rejection<br>Ratio                 | (See Graph)              | 40   | 56        |      | dB    |

<sup>3.</sup> Guaranteed by design and/or characterization.

**AC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +2.5 V,  $V_{EE}$  = -2.5 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 150  $\Omega$  to GND,  $R_F$  = 150  $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

| Symbol                        | Characteristic  | Conditions   | Min | Тур        | Max | Unit   |
|-------------------------------|---|--|-----|------------|-----|--------|
| FREQUENC                      | CY DOMAIN PERFORMANCE                                   |  | •   | •          | •   | •      |
| BW                            | Bandwidth<br>3.0 dB Small Signal<br>3.0 dB Large Signal | $A_V = +2.0, V_O = 0.5 V_{p-p}$<br>$A_V = +2.0, V_O = 1.0 V_{p-p}$ |     | 550<br>200 |     | MHz    |
| GF <sub>0.1dB</sub>           | 0.1 dB Gain Flatness<br>Bandwidth                       | A <sub>V</sub> = +2.0  |     | 35         |     | MHz    |
| dG                            | Differential Gain                                       | $A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$                       |     | 0.07       |     | %      |
| dΡ                            | Differential Phase                                      | $A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$                       |     | 0.02       |     | ٥      |
| TIME DOM                      | AIN RESPONSE  |  |     |            |     |        |
| SR                            | Slew Rate   | A <sub>V</sub> = +2.0, V <sub>step</sub> = 1.0 V                   |     | 900        |     | V/μs   |
| t <sub>s</sub>                | Settling Time 0.1%                                      | A <sub>V</sub> = +2.0, V <sub>step</sub> = 1.0 V                   |     | 10         |     | ns     |
| t <sub>r</sub> t <sub>f</sub> | Rise and Fall Time                                      | (10%-90%) A <sub>V</sub> = +2.0, V <sub>step</sub> = 1.0 V         |     | 1.7        |     | ns     |
| t <sub>ON</sub>               | Turn-on Time  |  |     | 5.0        |     | ns     |
| t <sub>OFF</sub>              | Turn-off Time   |  |     | 15         |     | ns     |
| HARMONIC                      | NOISE PERFORMANCE                                       |  |     |            |     |        |
| THD                           | Total Harmonic Distortion                               | $f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$                           |     | -60        |     | dB     |
| HD2                           | 2nd Harmonic Distortion                                 | $f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$                           |     | -65        |     | dBc    |
| HD3                           | 3rd Harmonic Distortion                                 | $f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$                           |     | -63        |     | dBc    |
| IP3                           | Third-Order Intercept                                   | $f = 10 \text{ MHz}, V_O = 0.5 V_{p-p}$                            |     | 35         |     | dBm    |
| SFDR                          | Spurious-Free Dynamic<br>Range                          | $f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$                           |     | 63         |     | dBc    |
| e <sub>N</sub>                | Input Referred Voltage Noise                            | f = 1.0 MHz  |     | 5.0        |     | nV/√Hz |
| i <sub>N</sub>                | Input Referred Current Noise                            | f = 1.0 MHz  |     | 4.0        |     | pA/√Hz |

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +2.5 V,  $V_{EE}$  = -2.5 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 150  $\Omega$  to GND,  $R_F$  = 150  $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

| Symbol                   | Characteristic                                  | Conditions               | Min   | Тур       | Max  | Unit  |
|--------------------------|---|--------------------------|-------|-----------|------|-------|
| DC PERFO                 | RMANCE  |                          |       |           |      |       |
| V <sub>IO</sub>          | Input Offset Voltage                            |                          | -10   | 0         | +10  | mV    |
| $\Delta V_{IO}/\Delta T$ | Input Offset Voltage<br>Temperature Coefficient |                          |       | 6.0       |      | μV/°C |
| I <sub>IB</sub>          | Input Bias Current                              | V <sub>O</sub> = 0 V     |       | ±3.2      | ± 20 | μΑ    |
| $\Delta I_{IB}/\Delta T$ | Input Bias Current<br>Temperature Coefficient   | V <sub>O</sub> = 0 V     |       | ± 40      |      | nA/°C |
| $V_{IH}$                 | Input High Voltage (Enable)<br>(Note 3)         |                          | 1.5   |           |      | V     |
| V <sub>IL</sub>          | Input Low Voltage (Enable)<br>(Note 3)          |                          |       |           | 0.5  | V     |
| INPUT CHA                | ARACTERISTICS                                   |                          |       |           |      |       |
| $V_{CM}$                 | Input Common Mode Voltage<br>Range (Note 3)     |                          | ±1.1  | ±1.6      |      | V     |
| CMRR                     | Common Mode Rejection<br>Ratio                  | (See Graph)              | 40    | 50        |      | dB    |
| R <sub>IN</sub>          | Input Resistance                                |                          |       | 4.5       |      | МΩ    |
| C <sub>IN</sub>          | Differential Input<br>Capacitance               |                          |       | 1.0       |      | pF    |
| оитрит с                 | HARACTERISTICS                                  |                          |       |           |      |       |
| R <sub>OUT</sub>         | Output Resistance                               | Closed Loop<br>Open Loop |       | 0.1<br>13 |      | Ω     |
| Vo                       | Output Voltage Range                            |                          | ± 1.1 | ±1.6      |      | V     |
| I <sub>O</sub>           | Output Current                                  |                          | ±50   | ±100      |      | mA    |
| POWER SU                 | JPPLY   |                          |       |           |      |       |
| Vs                       | Operating Voltage Supply                        |                          |       | 5.0       |      | V     |
| I <sub>S,ON</sub>        | Power Supply Current –<br>Enabled               |                          | 5.0   | 11.5      | 17   | mA    |
| I <sub>S,OFF</sub>       | Power Supply Current –<br>Disabled              |                          |       | 0.5       | 0.8  | mA    |
| PSRR                     | Power Supply Rejection<br>Ratio                 | (See Graph)              | 40    | 56        |      | dB    |

<sup>4.</sup> Guaranteed by design and/or characterization.

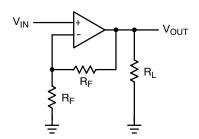
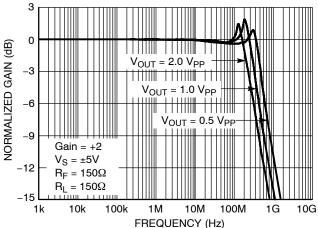
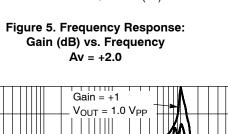


Figure 4. Typical Test Setup (A<sub>V</sub> = +2.0, R<sub>F</sub> = 1.0 k $\Omega$ , R<sub>L</sub> = 100  $\Omega$ )





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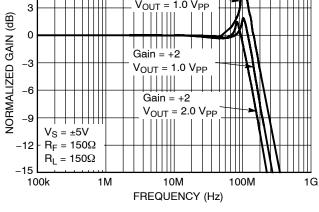


Figure 7. Large Signal Frequency Response Gain (dB) vs. Frequency

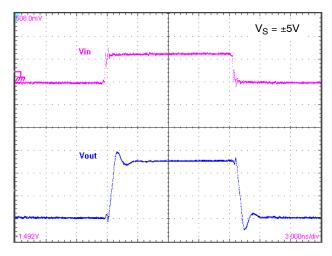


Figure 9. Small Signal Step Response Vertical: 20 mV/div Horizontal: 3 ns/div

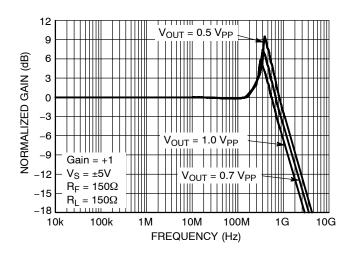


Figure 6. Frequency Response: Gain (dB) vs. Frequency Av = +1.0

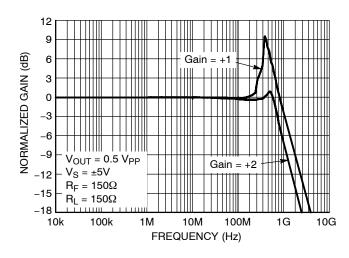


Figure 8. Small Signal Frequency Response Gain (dB) vs. Frequency

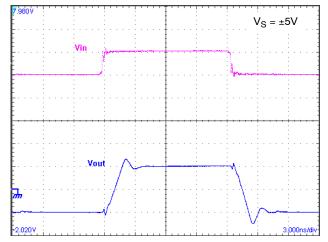
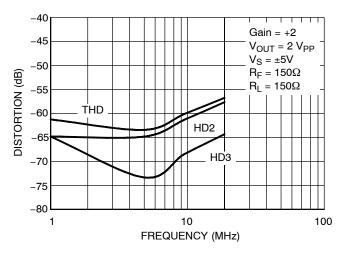


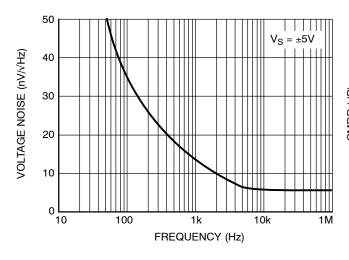
Figure 10. Large Signal Step Response Vertical: 1 V/div Horizontal: 3 ns/div



-40 Gain = +2-45 Freq = 5 MHz  $V_S = \pm 5V$ -50  $R_F^- = 150\Omega$ DISTORTION (dB)  $R_L = 150\Omega$ -55 -60 THD HD2 -65 -70 HD3 -75 -80 0.5 2.5 3 3.5 4.5 0 1 1.5 2 4 V<sub>OUT</sub> (V<sub>PP</sub>)

Figure 11. THD, HD2, HD3 vs. Frequency

Figure 12. THD, HD2, HD3 vs. Output Voltage



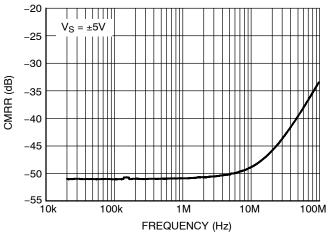
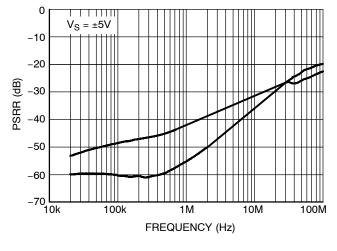


Figure 13. Input Referred Voltage Noise vs. Frequency

Figure 14. CMRR vs. Frequency



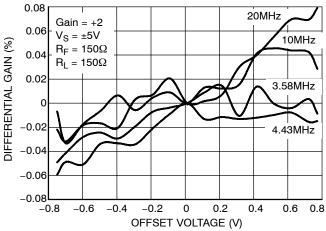


Figure 15. PSRR vs. Frequency

Figure 16. Differential Gain

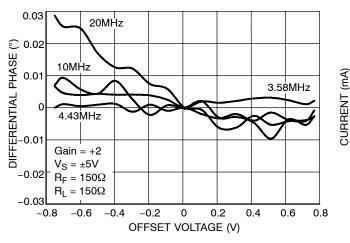


Figure 17. Differential Phase

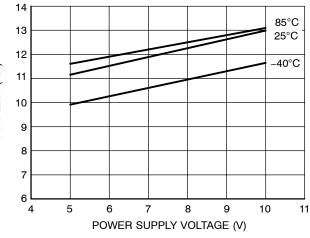


Figure 18. Supply Current vs. Power Supply (Enabled)

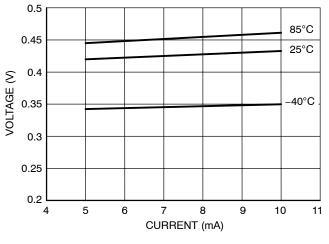


Figure 19. Supply Current (Disabled)

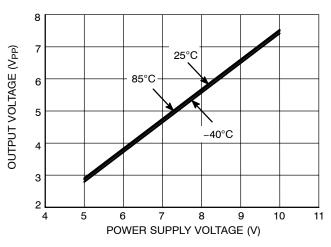


Figure 20. Output Voltage Swing vs. Supply Voltage

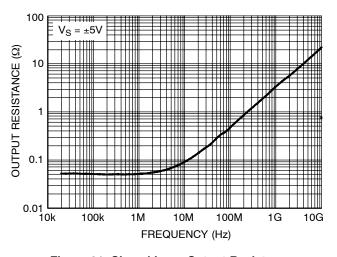


Figure 21. Closed Loop Output Resistance vs. Frequency

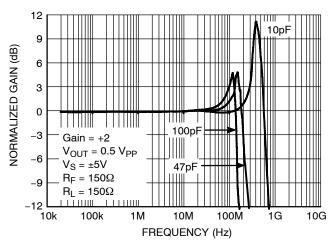
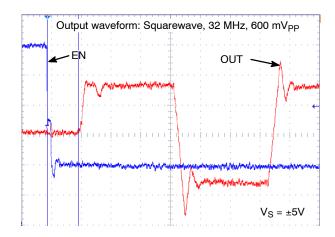


Figure 22. Frequency Response vs. Capacitive Load



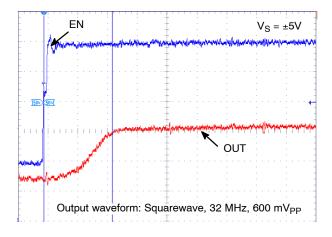


Figure 23. Turn ON Time Delay Vertical: 500 mV/div (Enable), 200 mV/div (Output) Horizontal: 5 ns/div

Figure 24. Turn OFF Time Delay Vertical: 500 mV/div (Enable), 200 mV/div (Output) Horizontal: 5 ns/div

# **Printed Circuit Board Layout Techniques**

Proper high speed PCB design rules should be used for all wideband amplifiers as the PCB parasitics can affect the overall performance. Most important are stray capacitances at the output and inverting input nodes as it can effect peaking and bandwidth. A space (3/16" is plenty) should be left around the signal lines to minimize coupling. Also, signal lines connecting the feedback and gain resistors should be short enough so that their associated inductance does not cause high frequency gain errors. Line lengths less than 1/4" are recommended.

#### **Video Performance**

This device designed to provide good performance with NTSC, PAL, and HDTV video signals. Best performance is obtained with back terminated loads as performance is degraded as the load is increased. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage.

#### **ESD Protection**

All device pins have limited ESD protection using internal diodes to power supplies as specified in the attributes table (see Figure 25). These diodes provide moderate protection

to input overdrive voltages above the supplies. The ESD diodes can support high input currents with current limiting series resistors. Keep these resistor values as low as possible since high values degrade both noise performance and frequency response. Under closed—loop operation, the ESD diodes have no effect on circuit performance. However, under certain conditions the ESD diodes will be evident. If the device is driven into a slewing condition, the ESD diodes will clamp large differential voltages until the feedback loop restores closed—loop operation. Also, if the device is powered down and a large input signal is applied, the ESD diodes will conduct.

NOTE: Human Body Model for +IN and –IN pins are rated at 0.8kV while all other pins are rated at 2.0kV.

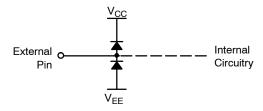


Figure 25. Internal ESD Protection

## **ORDERING INFORMATION**

| Device       | Package                       | Shipping <sup>†</sup> |
|--------------|-------------------------------|-----------------------|
| NCS2552SNT1G | SOT23-6 (TSOP-6)<br>(Pb-Free) | 3000 Tape & Reel      |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





NOTE 5

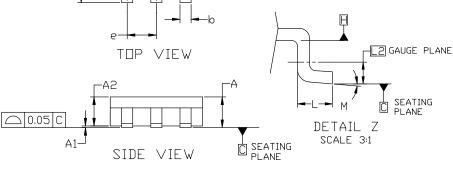
### TSOP-6 3.00x1.50x0.90, 0.95P **CASE 318G ISSUE W**

**DATE 26 FEB 2024** 

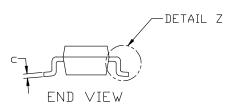


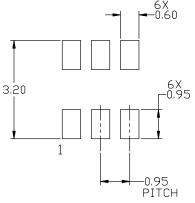
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
- CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM
  LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.

  5. PIN 1 INDICATOR MUST BE LOCATED IN THE INDICATED ZONE



| N   | MILLIMETERS |          |      |  |  |  |  |
|-----|-------------|----------|------|--|--|--|--|
| DIM | MIN         | NDM      | MAX  |  |  |  |  |
| Α   | 0.90        | 1.00     | 1.10 |  |  |  |  |
| A1  | 0.01        | 0.06     | 0.10 |  |  |  |  |
| A2  | 0.80        | 0.90     | 1.00 |  |  |  |  |
| b   | 0.25        | 0.38     | 0.50 |  |  |  |  |
| C   | 0.10        | 0.18     | 0.26 |  |  |  |  |
| D   | 2.90        | 3.00     | 3.10 |  |  |  |  |
| E   | 2.50        | 2.75     | 3.00 |  |  |  |  |
| E1  | 1.30        | 1.50     | 1.70 |  |  |  |  |
| е   | 0.85        | 0.95     | 1.05 |  |  |  |  |
| L   | 0.20        | 0.40     | 0.60 |  |  |  |  |
| L2  | (           | 0,25 BS0 | 2    |  |  |  |  |
| М   | 0°          |          | 10°  |  |  |  |  |





### RECOMMENDED MOUNTING FOOTPRINT

\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference manual, SDLDERRM/D.

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|------------------|---------------------------|---|--|--|--|
| DESCRIPTION:     | TSOP-6 3.00x1.50x0.90, 0. | TSOP-6 3.00x1.50x0.90, 0.95P  |  |  |  |

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## TSOP-6 3.00x1.50x0.90, 0.95P CASE 318G

ISSUE W

**DATE 26 FEB 2024** 

# GENERIC MARKING DIAGRAM\*



XXX = Specific Device Code

e XXX = Specific Device Code

A =Assembly Location

M = Date Code= Pb-Free Package

Y = Year

- - - 1 L

W = Work Week

= Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

| STYLE 1:<br>PIN 1. DRAIN<br>2. DRAIN<br>3. GATE<br>4. SOURCE<br>5. DRAIN<br>6. DRAIN              | STYLE 2: PIN 1. EMITTER 2 2. BASE 1 3. COLLECTOR 1 4. EMITTER 1 5. BASE 2 6. COLLECTOR 2    | STYLE 3: PIN 1. ENABLE 2. N/C 3. R BOOST 4. Vz 5. V in 6. V out                            | STYLE 4: PIN 1. N/C 2. V in 3. NOT USED 4. GROUND 5. ENABLE 6. LOAD                      | STYLE 5: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2 | STYLE 6: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR |
|---|---|--|--|--|---|
| STYLE 7: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. N/C 5. COLLECTOR 6. EMITTER                     | STYLE 8: PIN 1. Vbus 2. D(in) 3. D(in)+ 4. D(out)+ 5. D(out) 6. GND                         | STYLE 9: PIN 1. LOW VOLTAGE GATE 2. DRAIN 3. SOURCE 4. DRAIN 5. DRAIN 6. HIGH VOLTAGE GATE | STYLE 10:<br>PIN 1. D(OUT)+<br>2. GND<br>3. D(OUT)-<br>4. D(IN)-<br>5. VBUS<br>6. D(IN)+ | STYLE 11: PIN 1. SOURCE 1 2. DRAIN 2 3. DRAIN 2 4. SOURCE 2 5. GATE 1 6. DRAIN 1/GATE 2  | STYLE 12:<br>PIN 1. I/O<br>2. GROUND<br>3. I/O<br>4. I/O<br>5. VCC<br>6. I/O        |
| STYLE 13:<br>PIN 1. GATE 1<br>2. SOURCE 2<br>3. GATE 2<br>4. DRAIN 2<br>5. SOURCE 1<br>6. DRAIN 1 | STYLE 14: PIN 1. ANODE 2. SOURCE 3. GATE 4. CATHODE/DRAIN 5. CATHODE/DRAIN 6. CATHODE/DRAIN |  | E 16: 1. ANODE/CATHODE 2. BASE 3. EMITTER 4. COLLECTOR 5. ANODE 6. CATHODE               | STYLE 17: PIN 1. EMITTER 2. BASE 3. ANODE/CATHODE 4. ANODE 5. CATHODE 6. COLLECTOR       |   |

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|------------------|------------------------------|---|-------------|
| DESCRIPTION:     | TSOP-6 3.00x1.50x0.90, 0.95P |   | PAGE 2 OF 2 |

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